Docket No.

241807US2 DIV

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Toshiaki IWAMATSU et al.

SERIAL NO: New Application

GAU:

FILED:

Herewith

**EXAMINER:** 

FOR:

SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

# **INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

#### REFERENCES

The applicant(s) wish to make of record the references listed on the attached form PTO-1449 that were cited in the
parent application Serial No. 09/985,020, filed November 1, 2001. Copies of the listed references were filed in the
parent application.

☐ A check is attached in the amount required under 37 CFR §1.17(p).

#### **RELATED CASES**

Attached is a list of applicant's pending application(s) or issued patent(s) which may be related to the present
application. A copy of the patent(s), together with a copy of the claims and drawings of the pending application(s)
is attached along with PTO 1449.

☐ A check is attached in the amount required under 37 CFR §1.17(p).

#### **CERTIFICATION**

Each item of information contained in this information disclosure statement was first cited in a communication
from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of
this statement.

No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

### **DEPOSIT ACCOUNT**

Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment form is enclosed herewith, or credit any overpayment to deposit account number 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

Customer Number

22850

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Registration No. 28,870

Form PTO 1449		U.S. DEPARTMENT		ATTY DOCKET NO. SERIAL NO.				
(Modified) PATENT AND TRADEMARK OFFICE				241807US2DIV		New Application		
				APPLICANT				
LIST OF F	REFER	ENCES CITED BY A	PPLICANT	Toshiaki IWAMATSU et al.				
				FILING DATE		GROUP		
				Herewith				
···				U.S. PATENT DOCUMENTS				
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS		DATE OPRIATE
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		DOO! INSTALT		TRANSLATION				
		DOCUMENT NUMBER	DATE	COUNTRY		YES		NO
	AQ	2-159035	06/19/90	JAPAN (w/ English Extract)				X
	AP	9-275134	10/21/97	JAPAN (w/ English Extract)				X
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	AR							
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	AZ			Additional References sheet(s) atta			et(s) attache	
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